



# Optimizing Flash Controller Technology for Next-Gen Flash

Greg Huff, CTO, LSI

- Don't Be the Bottleneck
- All Markets Need Power Reduction
- Faster Wakeup Times
- Improve Flash Error Correction
- Extend Flash Endurance

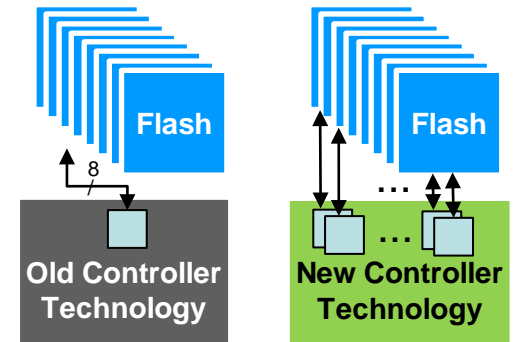
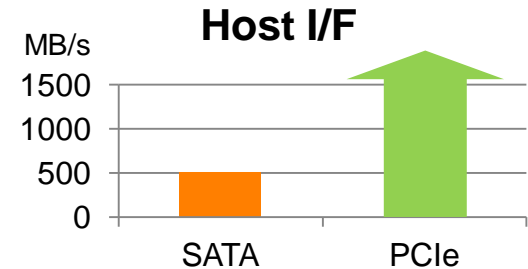
# Don't Be the Bottleneck



Controllers need to keep both host and flash interfaces at max speed

# Don't Be the Bottleneck

- SATA is limited to 500MB/s
  - Add native PCIe for >3x performance increase
- Maximize parallelism of flash channels
  - Make them independently controlled
- If using DRAM, running user data through it has a large cost
  - Full speed requires 2x host bandwidth
  - Increases costs and power consumption
  - Prevents true DevSleep ability



Push the bottleneck to the interfaces (host or flash)

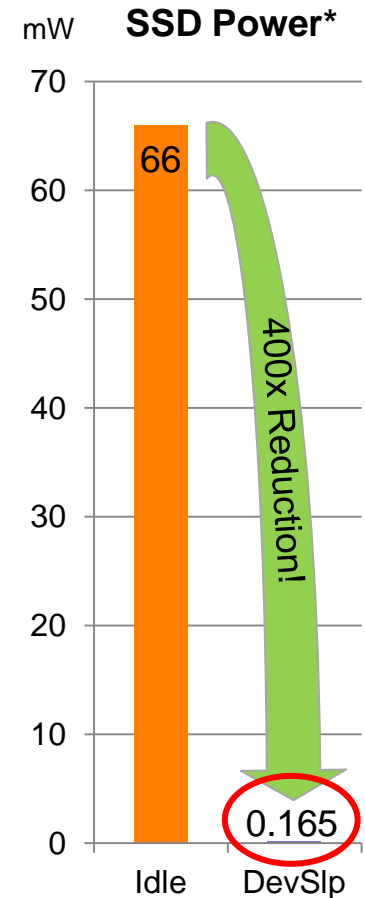
# All Markets Need Power Reduction



Future SSD performance must be “power efficient”, not “power wasteful!”



- Need more performance without burning power
- Everything is going “green”
  - Ultrabooks and Connected Standby
  - Datacenter buildings are typically power-capped
- Keep active power as low as possible
  - Avoid extra power of DRAM
  - Reduce data transfer times (consider GB/watt and IOPS/watt)
- Leverage DevSleep and low power modes
  - LSI showed 400x idle power reduction at Computex
- Reduce leakage
  - Design hardware to minimize leakage
  - Consider low power nodes like 40LP



Power reduction is an ongoing industry challenge

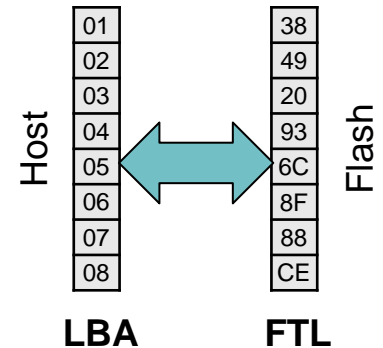
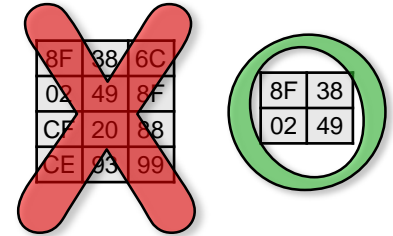
# Faster Wakeup Times



“Launch” from a dead stop as fast as possible

# Faster Wakeup Times

- Transition between power states quickly
  - Minimize state information
  - Reduce data restore times after wake
  - Improve recovery time
- Optimize Flash Translation Layer (FTL)
  - Reduce response time to host request immediately following wake up
  - Requires optimizing map architecture



Nirvana would be instant on from zero power!



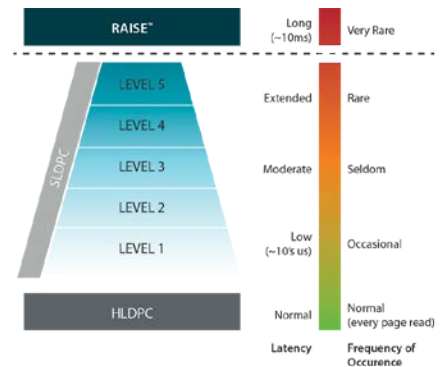
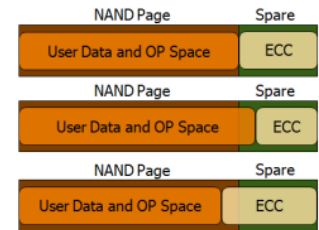
# Improve Flash Error Correction



New flash requires more difficult “repairs”

# Improve Flash Error Correction

- Lower NAND technology nodes increase error rates
- Stronger BCH requires too many spare bytes vs. LDPC
- LDPC & DSP technology becoming popular, but requires sophisticated soft-decision processing
  - Limit hard-decision processing to streamline most reads
  - Consider multiple code rates over flash life
  - Minimize number of read retries required to correct data
- Optimize time-to-data
- Add a higher level correction capability when ECC fails
- Create a NAND flash qualification team
  - Staff at double-digit manpower
  - Perform in-depth flash analysis across all vendors
  - Work closely with all flash manufacturers



LSI SHIELD™ Error Correction Technology is an example of leading edge LDPC and DSP correction technology

Not all LDPC is created equal – the actual soft-decision processing is key

# Extend Flash Endurance



Strengthen the underlying “roadway” and use it more “efficiently”

# Extend Flash Endurance

## NAND Trend

Higher error rate =  
lower endurance

Limited Factory  
P/E Cycles

Lifetime  
data written

Increase P/E Cycles with Much Better ECC

Write  
less

Additional data that can be written over the life of the  
flash memory

- Increased ECC ability extends recoverable reads
- Write less data to flash, but keep the same info!
  - Use data reduction technology like DuraWrite™
  - Higher performance from writing less
  - Increases Dynamic OP which reduces Write Amp
  - Also reduces power draw from less prog. time
- Avoid background garbage collection
  - It increases Write Amp which accelerates wear

Read better to read longer, and write less to write more

# Summary

- Push the bottleneck to the interfaces (host and flash)
- Power reduction is an ongoing industry challenge
- “Launch” from a dead stop as fast as possible
- LDPC is key to robust error correction, but not all LDPC solutions are created equal
- Increase flash endurance with better ECC and write more efficiently



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